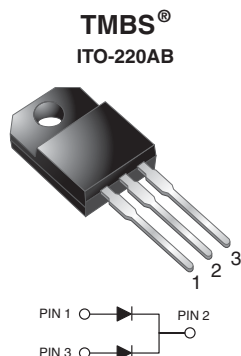


Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.34$ V at $I_F = 2.5$ A



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 5.0 A
V_{RRM}	45 V
I_{FSM}	100 A
V_F at $I_F = 5.0$ A	0.41 V
T_{OP} max. (AC mode)	150 °C
T_J max. (DC forward current)	200 °C
Package	ITO-220AB
Circuit configuration	Common cathode

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)			
PARAMETER	SYMBOL	VFT1045CBP	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum average forward rectified current (fig. 1) per device per diode	$I_{F(AV)}$ ⁽¹⁾	10 5.0	A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	100	A
Isolation voltage from terminal to heatsink, $t = 1$ min	V_{AC}	1500	V
Operating junction and storage temperature range (AC mode)	T_{OP}, T_{STG}	-40 to +150	°C
Junction temperature in DC forward current without reverse bias, $t \leq 1$ h	T_J ⁽²⁾	≤ 200	°C

Notes

⁽¹⁾ With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 2.5 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V
	I _F = 5.0 A			0.49	0.58	
	I _F = 2.5 A	T _A = 125 °C		0.34	-	
	I _F = 5.0 A			0.41	0.50	
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	500	μA
		T _A = 125 °C		5	15	mA

Notes

⁽¹⁾ Pulse test: 300 μ s pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width ≤ 40 ms



THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	VFT1045CBP	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	6.5	$^{\circ}\text{C/W}$
	per device		5.0	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VFT1045CBP-M3/4W	1.75	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

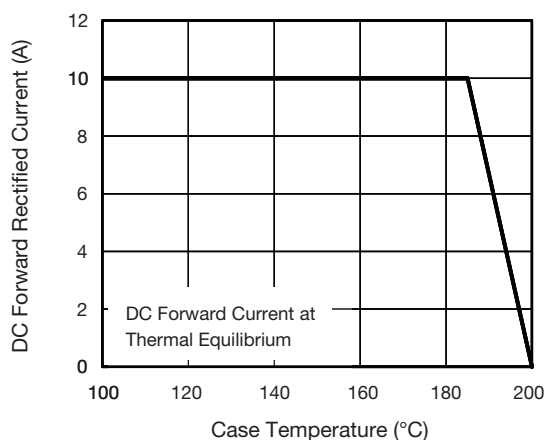


Fig. 1 - Maximum Forward Current Derating Curve

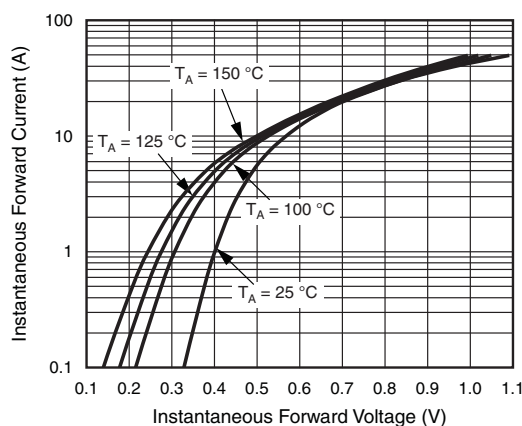


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

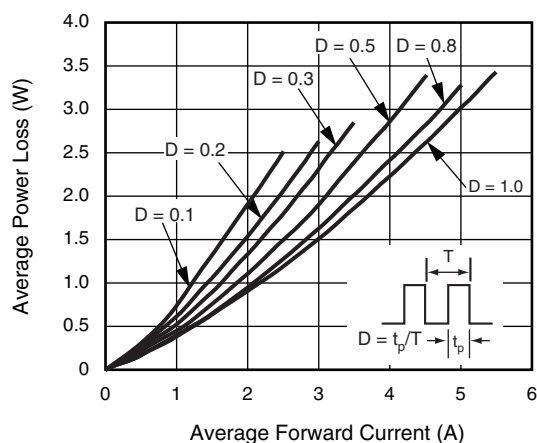


Fig. 2 - Forward Power Loss Characteristics Per Diode

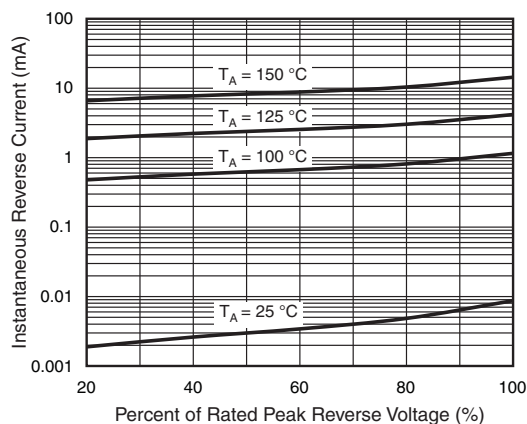


Fig. 4 - Typical Reverse Characteristics Per Diode

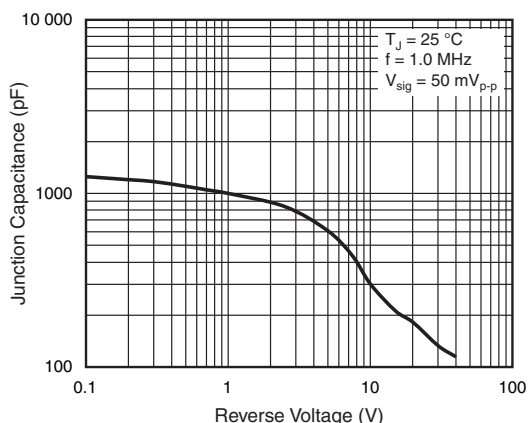


Fig. 5 - Typical Junction Capacitance Per Diode

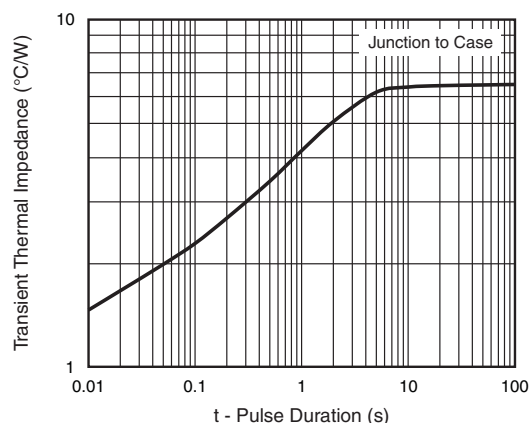
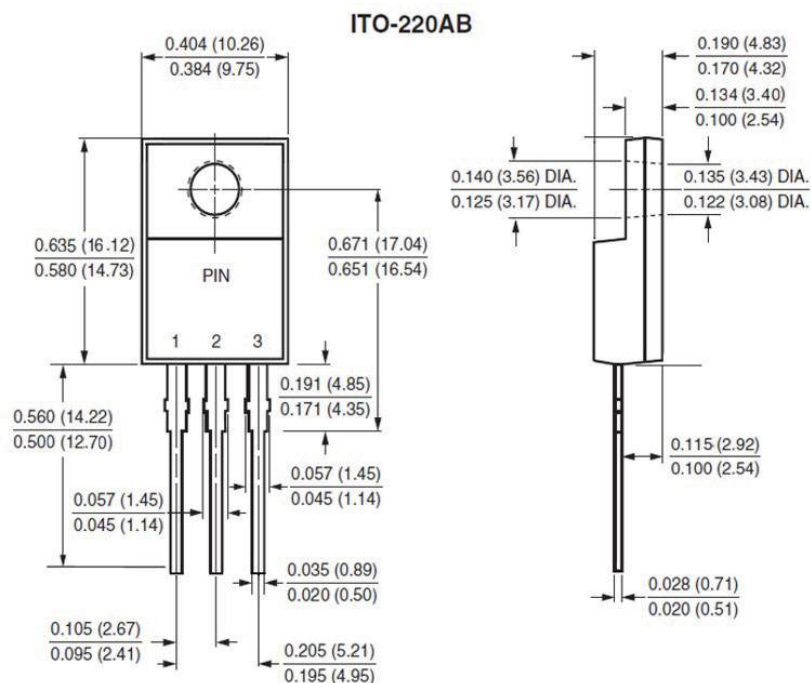


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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